
3-wire Automotive Temperature Serial EEPROMs
1K (128 x 8 or 64 x 16)

DATASHEET

Features

- Medium-voltage and Standard-voltage Operation
 - 2.5 ($V_{CC} = 2.5V$ to $5.5V$)
- User-selectable Internal Organization
 - 1K: 128 x 8 or 64 x 16
- 3-wire Serial Interface
- 2MHz Clock Rate (5V)
- Self-timed Write Cycle (10ms max)
- High Reliability
 - Endurance: 1,000,000 Write Cycles
 - Data Retention: 100 Years
- 8-lead JEDEC SOIC and TSSOP Packages

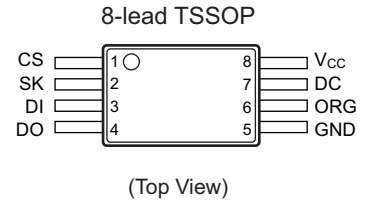
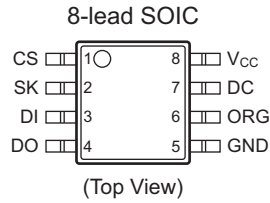
Description

The AT93C46D provides 1,024 bits of serial electrically erasable programmable read only memory (EEPROM) organized as 64 words of 16 bits each, when the ORG pin is connected to V_{CC} and 128 words of 8 bits each when it is tied to ground. The device is optimized for use in many automotive applications where low power and low voltage operations are essential. The AT93C46D is available in space-saving 8-lead TSSOP and 8-lead JEDEC SOIC packages. The AT93C46D is enabled through the Chip Select pin (CS), and accessed via a 3-wire serial interface consisting of Data Input (DI), Data Output (DO), and Shift Clock (SK). Upon receiving a READ instruction at DI, the address is decoded and the data is clocked out serially on the data output pin DO. The WRITE cycle is completely self-timed and no separate erase cycle is required before write. The Write cycle is only enabled when it is in the Erase/Write Enable state. When CS is brought "high" following the initiation of a write cycle, the DO pin outputs the Ready/Busy status.

1. Pin Configurations and Pinouts

Table 1-1. Pin Configurations

Pin Name	Function
CS	Chip Select
DI	Serial Data Input
DO	Serial Data Output
GND	Ground
ORG	Internal Organization
SK	Serial Data Clock
V _{CC}	Power Supply



Note: Drawings are not to scale.

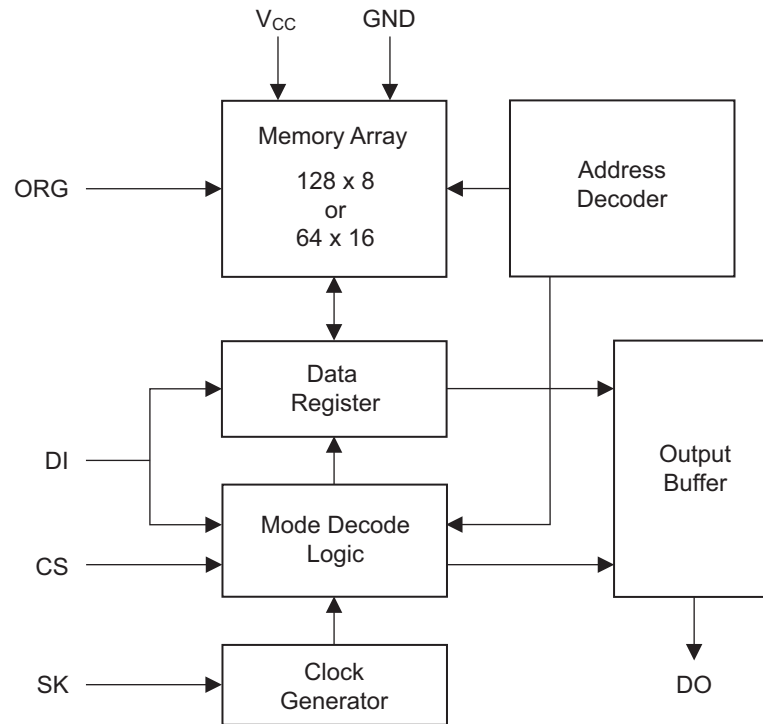
2. Absolute Maximum Ratings*

Operating Temperature	-55°C to +125°C
Storage Temperature	-65°C to +150°C
Voltage on Any Pin with Respect to Ground	-1.0V to +7.0V
Maximum Operating Voltage	6.25V
DC Output Current	.5.0mA

*Notice: Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability

3. Block Diagram

Figure 3-1. Block Diagram



Note: When the ORG pin is connected to V_{CC} , the x16 organization is selected. When it is connected to ground, the x8 organization is selected.

4. Memory Organization

4.1 Pin Capacitance

Table 4-1. Pin Capacitance⁽¹⁾

Applicable over recommended operating range from $T_A = 25^\circ\text{C}$, $f = 1.0\text{MHz}$, $V_{CC} = +5.0\text{V}$ (unless otherwise noted).

Symbol	Test Conditions	Max	Units	Conditions
C_{OUT}	Output Capacitance (DO)	5	pF	$V_{OUT} = 0\text{V}$
C_{IN}	Input Capacitance (CS, SK, DI)	5	pF	$V_{IN} = 0\text{V}$

Note: 1. This parameter is characterized and is not 100% tested.

4.2 DC Characteristics

Table 4-2. DC Characteristics

Applicable over recommended operating range from: $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{CC} = +2.5\text{V}$ to $+5.5\text{V}$ (unless otherwise noted).

Symbol	Parameter	Test Condition		Min	Typ	Max	Unit
V_{CC1}	Supply Voltage			2.5		5.5	V
V_{CC2}	Supply Voltage			4.5		5.5	V
I_{CC}	Supply Current	$V_{CC} = 5.0\text{V}$	Read at 1.0MHz		0.5	2.0	mA
			WRITE at 1.0MHz		0.5	2.0	mA
I_{SB1}	Standby Current	$V_{CC} = 2.5\text{V}$	CS = 0V		6.0	10.0	μA
I_{SB2}	Standby Current	$V_{CC} = 5.0\text{V}$	CS = 0V		10.0	15.0	μA
I_{IL}	Input Leakage	$V_{IN} = 0\text{V}$ to V_{CC}			0.1	1.0	μA
I_{OL}	Output Leakage	$V_{IN} = 0\text{V}$ to V_{CC}			0.1	1.0	μA
$V_{IL1}^{(1)}$	Input Low Voltage	$2.5\text{V} \leq V_{CC} \leq 5.5\text{V}$		-0.6		0.8	
$V_{IH1}^{(1)}$	Input High Voltage			2.0		$V_{CC} + 1$	V
V_{OL1}	Output Low Voltage	$2.5\text{V} \leq V_{CC} \leq 5.5\text{V}$	$I_{OL} = 2.1\text{mA}$			0.4	V
V_{OH1}	Output High Voltage		$I_{OH} = -0.4\text{mA}$	2.4			V

Note: 1. V_{IL} min and V_{IH} max are reference only and are not tested.

4.3 AC Characteristics

Table 4-3. AC Characteristics

Applicable over recommended operating range from $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{CC} = \text{As Specified}$, $C_L = 1$ TTL Gate and 100pF (unless otherwise noted).

Symbol	Parameter	Test Condition	Min	Typ	Max	Units
f_{SK}	SK Clock Frequency	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$	0		2	MHz
		$2.5\text{V} \leq V_{CC} \leq 5.5\text{V}$	0		1	
t_{SKH}	SK High Time	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$	250			ns
		$2.5\text{V} \leq V_{CC} \leq 5.5\text{V}$	250			
t_{SKL}	SK Low Time	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$	250			ns
		$2.5\text{V} \leq V_{CC} \leq 5.5\text{V}$	250			
t_{CS}	Minimum CS Low Time	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$	250			ns
		$2.5\text{V} \leq V_{CC} \leq 5.5\text{V}$	250			
t_{CSS}	CS Setup Time	Relative to SK	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$	50		ns
			$2.5\text{V} \leq V_{CC} \leq 5.5\text{V}$	50		
t_{DIS}	DI Setup Time	Relative to SK	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$	100		ns
			$2.5\text{V} \leq V_{CC} \leq 5.5\text{V}$	100		
t_{CSH}	CS Hold Time	Relative to SK	0			ns
t_{DIH}	DI Hold Time	Relative to SK	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$	100		ns
			$2.5\text{V} \leq V_{CC} \leq 5.5\text{V}$	100		
t_{PD1}	Output Delay to '1'	AC Test	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$		250	ns
			$2.5\text{V} \leq V_{CC} \leq 5.5\text{V}$		500	
t_{PD0}	Output Delay to '0'	AC Test	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$		250	ns
			$2.5\text{V} \leq V_{CC} \leq 5.5\text{V}$		500	
t_{SV}	CS to Status Valid	AC Test	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$		250	ns
			$2.5\text{V} \leq V_{CC} \leq 5.5\text{V}$		250	
t_{DF}	CS to DO in High-impedance	AC Test	$4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$		100	ns
		$CS = V_{IL}$	$2.5\text{V} \leq V_{CC} \leq 5.5\text{V}$		150	
t_{WP}	Write Cycle Time		$2.5\text{V} \leq V_{CC} \leq 5.5\text{V}$	3	10	ms
Endurance ⁽¹⁾	5.0V, 25°C			1,000,000		Write Cycles

Note: 1. This parameter is ensured by characterization only.

5. Instruction Set for the AT93C46D

Table 5-1. Instruction Set for the AT93C46D

Instruction	SB	Opcode	Address		Data		Comments
			x8	x16	x8	x16	
READ	1	10	$A_6 - A_0$	$A_5 - A_0$			Reads data stored in memory, at specified address.
EWEN	1	00	11XXXXXX	11XXXX			Write enable must precede all programming modes.
ERASE	1	11	$A_6 - A_0$	$A_5 - A_0$			Erase memory location $A_n - A_0$.
WRITE	1	01	$A_6 - A_0$	$A_5 - A_0$	$D_7 - D_0$	$D_{15} - D_0$	Writes memory location $A_n - A_0$.
ERAL	1	00	10XXXXXX	10XXXX			Erases all memory locations. Valid only at $V_{CC} = 4.5V$ to $5.5V$.
WRAL	1	00	01XXXXXX	01XXXX	$D_7 - D_0$	$D_{15} - D_0$	Writes all memory locations. Valid only at $V_{CC} = 4.5V$ to $5.5V$.
EWDS	1	00	00XXXXXX	00XXXX			Disables all programming instructions.

Note: The 'X' in the address field represent don't care values and must be clocked.

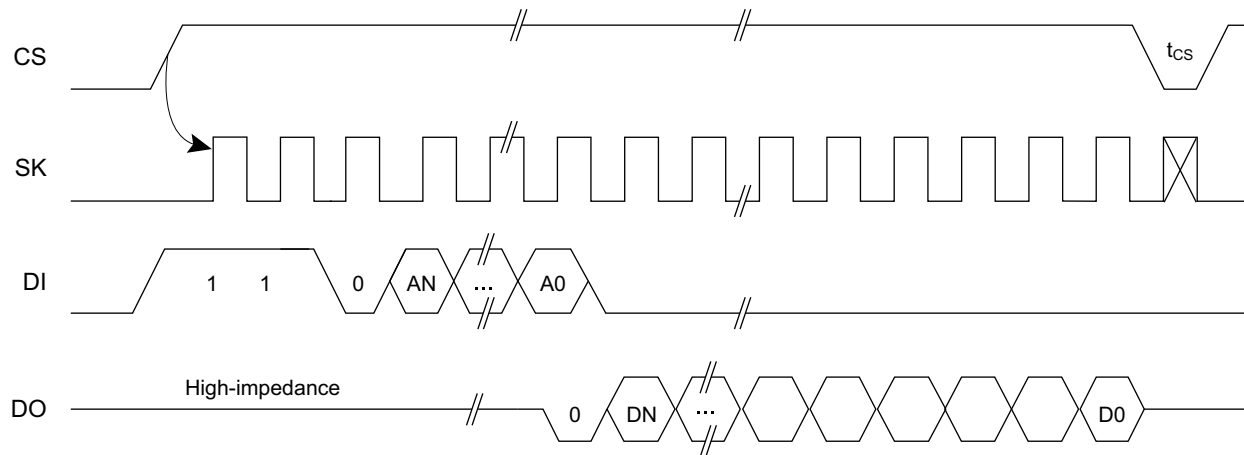
6. Functional Description

The AT93C46D is accessed via a simple and versatile 3-wire serial communication interface. The device operation is controlled by seven instructions issued by the host processor. A *valid instruction starts with a rising edge of CS* and consists of a Start bit (Logic 1) followed by the appropriate Opcode and the desired memory Address location.

READ: The READ instruction contains the address code for the memory location to be read. After the instruction and address are decoded, data from the selected memory location is available at the Serial Output (DO) pin. Output data changes are synchronized with the rising edges of Serial Clock (SK).

Note: A dummy bit (Logic 0) precedes the 8- or 16-bit data output string.

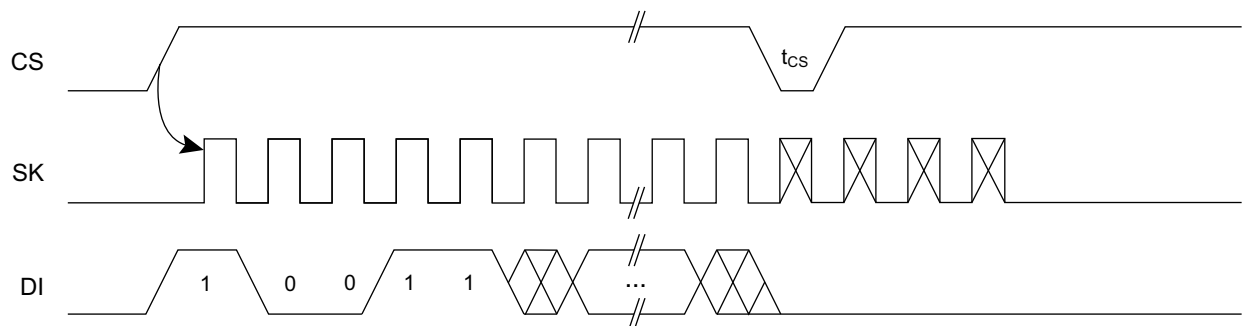
Figure 6-1. Read Timing



ERASE/WRITE (EWEN): To assure data integrity, the part automatically goes into the Erase/Write Disable (EWDS) state when the power is first applied. An EWEN instruction must be executed first before any programming instructions can be carried out.

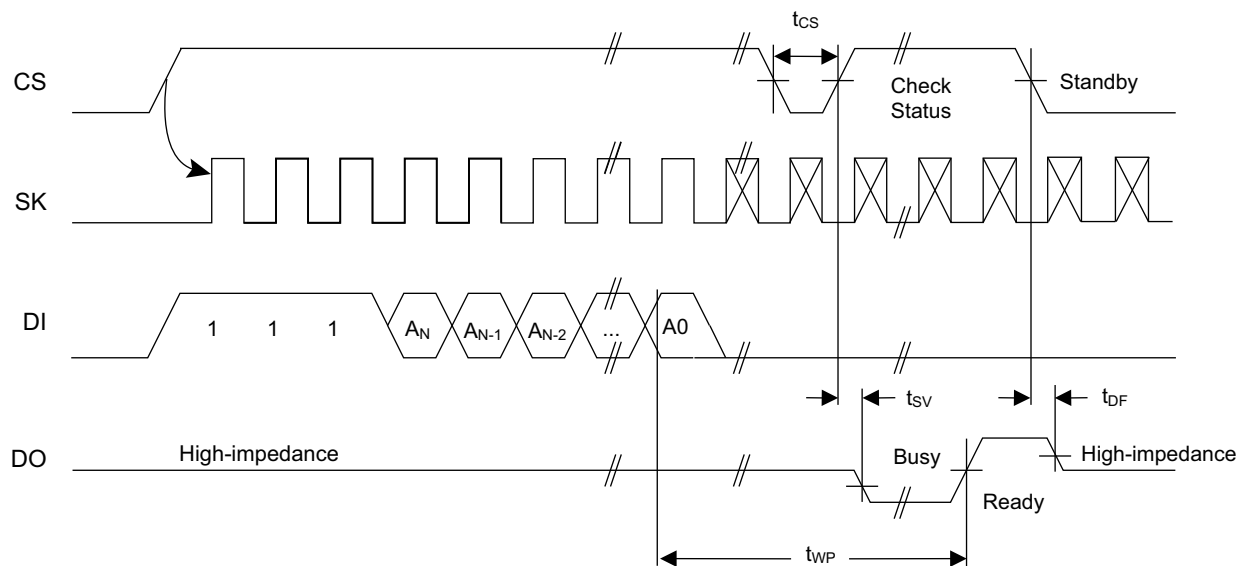
Note: Once in the EWEN state, programming remains enabled until an EWDS instruction is executed or V_{CC} power is removed from the part.

Figure 6-2. EWEN Timing



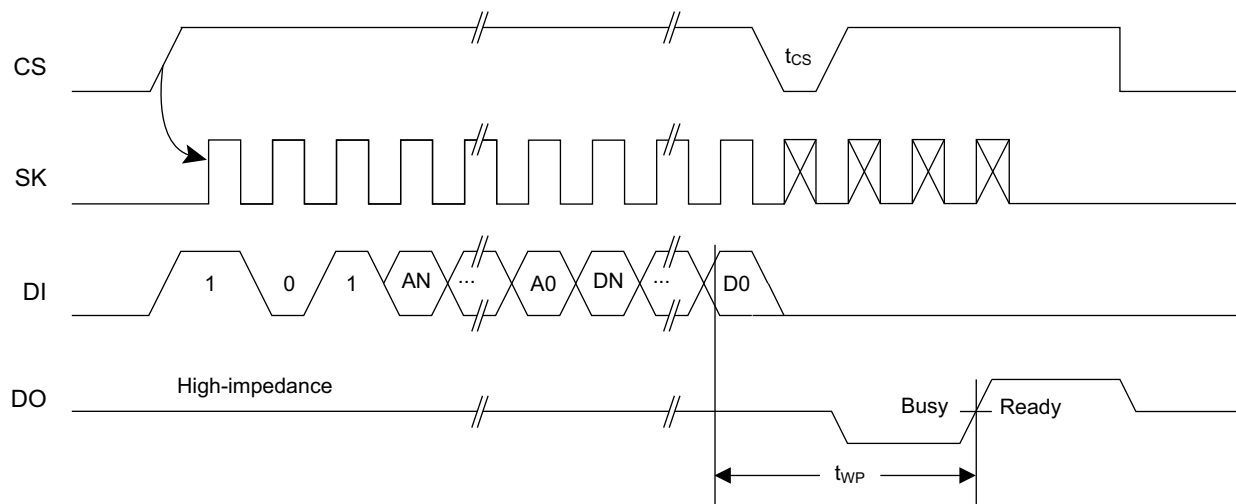
ERASE: The Erase instruction programs all of the bits in the specified memory location to the Logic 1 state. The self-timed erase cycle starts once the ERASE instruction and address are decoded. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250ns (t_{CS}). A Logic 1 at the DO pin indicates that the selected memory location has been erased, and the part is ready for another instruction.

Figure 6-3. ERASE Timing



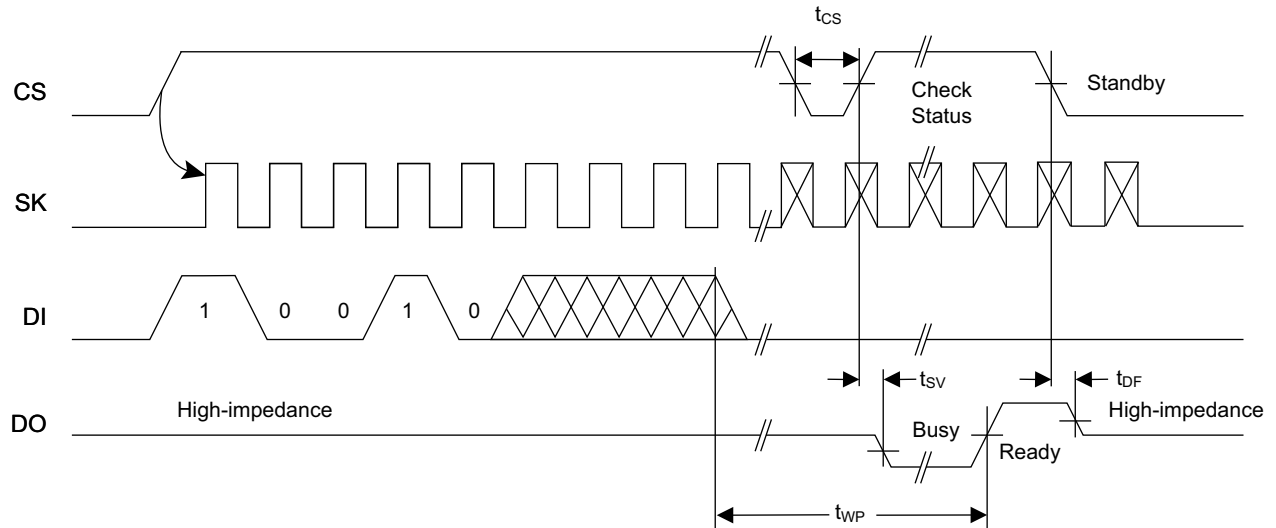
WRITE: The WRITE instruction contains the 8 or 16 bits of data to be written into the specified memory location. The self-timed programming cycle, t_{WP} , starts after the last bit of data is received at serial data input pin DI. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250ns (t_{CS}). A Logic 0 at DO indicates that programming is still in progress. A Logic 1 indicates that the memory location at the specified address has been written with the data pattern contained in the instruction and the part is ready for further instructions. *A Ready/Busy status cannot be obtained if the CS is brought high after the end of the self-timed programming cycle, t_{WP} .*

Figure 6-4. Write Timing



Erase All (ERAL): The ERAL instruction programs every bit in the memory array to the Logic 1 state and is primarily used for testing purposes. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250ns (t_{CS}). The ERAL instruction is valid only at $V_{CC} = 5.0V \pm 10\%$.

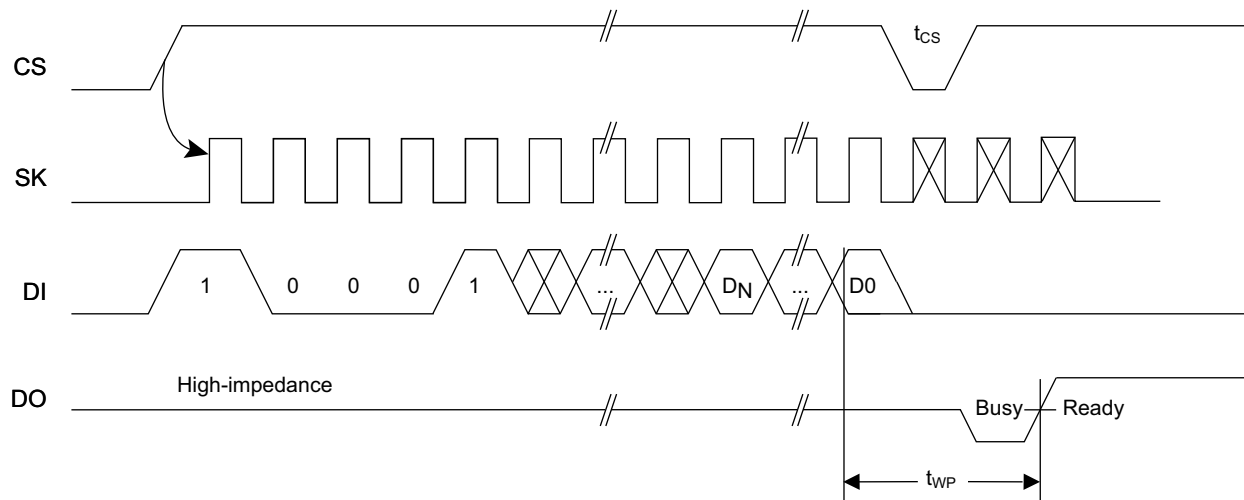
Figure 6-5. ERAL Timing⁽¹⁾



Note: 1. Valid only at $V_{CC} = 4.5V$ to $5.5V$.

WRITE ALL (WRAL): The WRAL instruction programs all memory locations with the data patterns specified in the instruction. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250 ns (t_{CS}). The WRAL instruction is valid only at $V_{CC} = 5.0V \pm 10\%$.

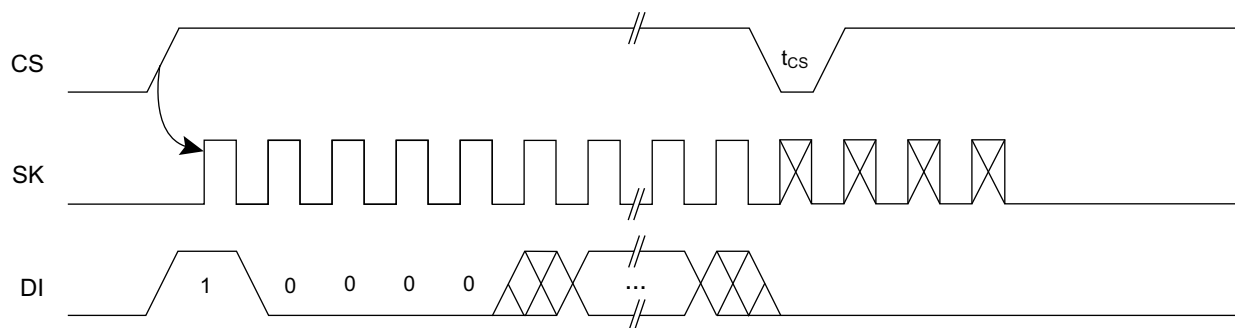
Figure 6-6. WRAL Timing⁽¹⁾



Note: 1. Valid only at $V_{CC} = 4.5V$ to $5.5V$.

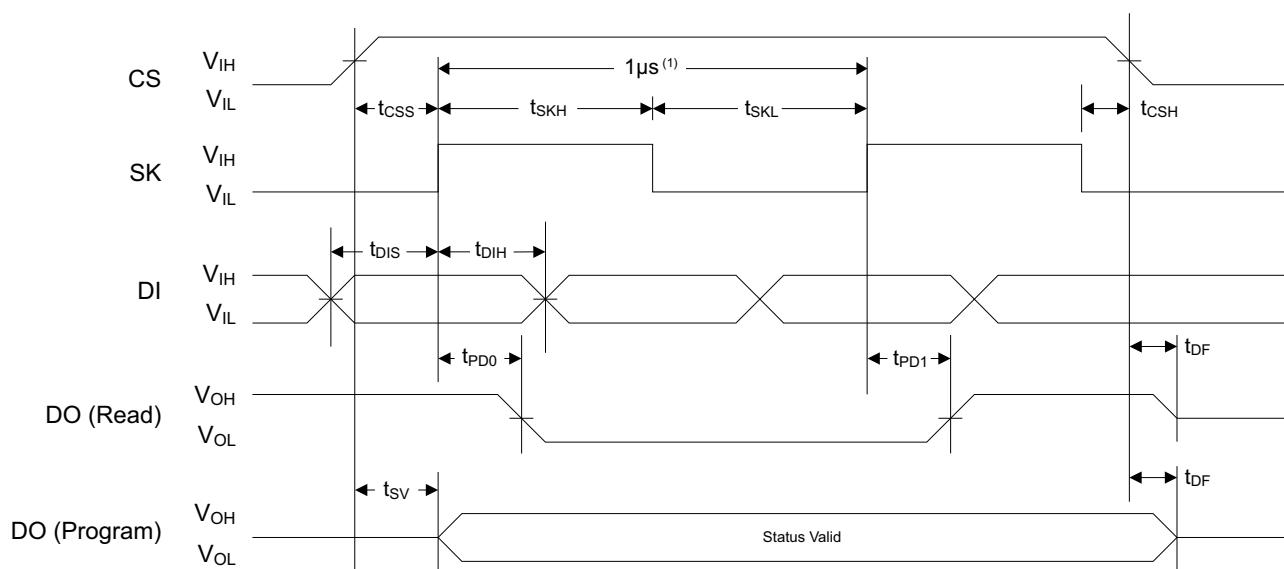
ERASE/WRITE DISABLE (EWDS): To protect against accidental data disturb, the EWDS instruction disables all the programming modes and should be executed after all programming operations. The operation of the READ instruction is independent of both the EWEN and EWDS instructions and can be executed at any time.

Figure 6-7. EWDS Timing



7. Timing Diagrams

Figure 7-1. Synchronous Data Timing

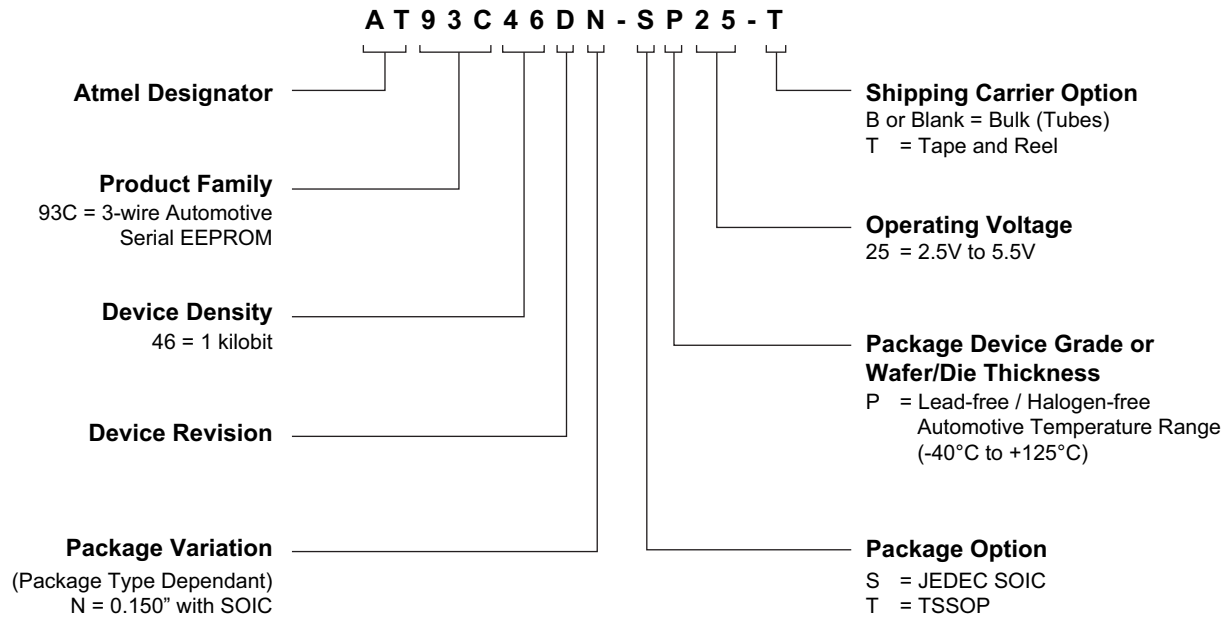


Note: 1. This is the minimum SK period.

Table 7-1. Organization Key for the Timing Diagrams

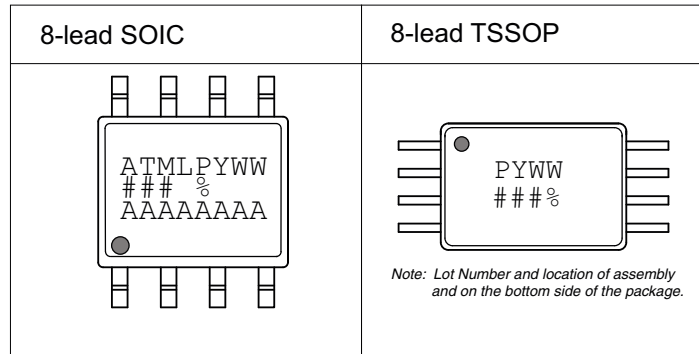
I/O	AT93C46D (1K)	
	x 8	x 16
A_N	A_6	A_5
D_N	D_7	D_{15}

8. Ordering Code Detail



9. Part Markings

AT93C46D: Automotive Package Marking Information



Note 1: ● designates pin 1

Note 2: Package drawings are not to scale

Catalog Number Truncation			
AT93C46D		Truncation Code ###: 46D	
Date Codes			Voltages
Y = Year	M = Month	WW = Work Week of Assembly	% = Minimum Voltage
4: 2014 8: 2018	A: January	02: Week 2	2: 2.5V min
5: 2015 9: 2019	B: February	04: Week 4	
6: 2016 0: 2020	
7: 2017 1: 2021	L: December	52: Week 52	
Country of Assembly		Lot Number	Grade/Lead Finish Material
@ = Country of Assembly		AAA...A = Atmel Wafer Lot Number	P: Automotive/NiPdAu
Trace Code			Atmel Truncation
XX = Trace Code (Atmel Lot Numbers Correspond to Code) Example: AA, AB.... YZ, ZZ			AT: Atmel ATM: Atmel ATML: Atmel

3/13/14

<p>Package Mark Contact: DL-CSO-Assy_eng@atmel.com</p>	TITLE 93C46DAM , AT93C46D Automotive Package Marking Information	DRAWING NO. 93C46DAM	REV. A
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10. Ordering Codes

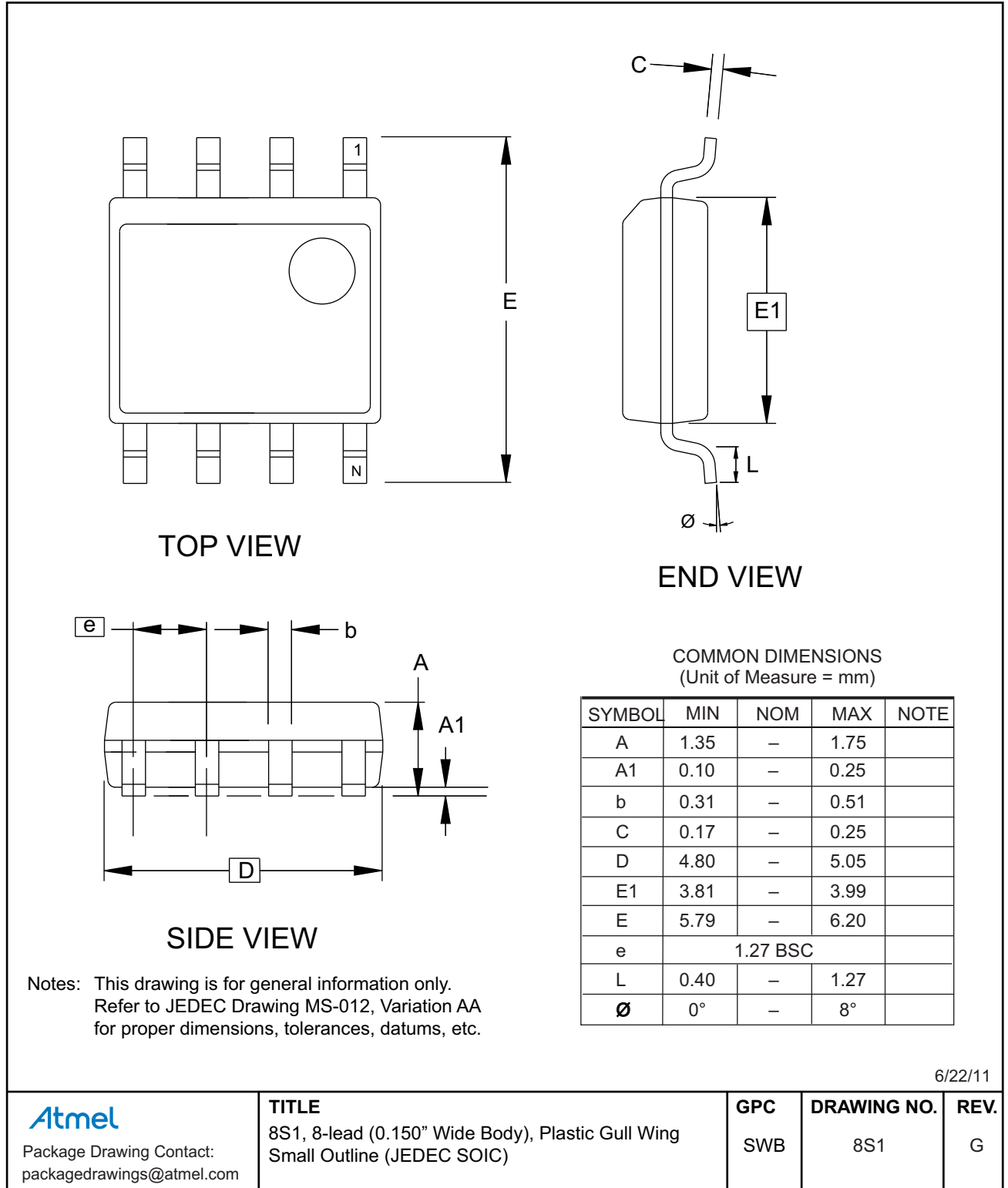
Atmel Ordering Code	Lead Finish	Package	Voltage	Operation Range
AT93C46DN-SP25-T ⁽¹⁾	Lead-free / Halogen-free	8S1	2.5V to 5.5V	Automotive Temperature (-40°C to 125°C)
AT93C46DN-SP25-B ⁽²⁾				
AT93C46D-TP25-T ⁽¹⁾		8X		
AT93C46D-TP25-B ⁽²⁾				

- Notes:
- Tape and reel delivery:
 - SOIC = 4,000 per reel.
 - TSSOP = 5,000 per reel.
 - Bulk delivery in tubes:
 - SOIC and TSSOP = 100 per tube.

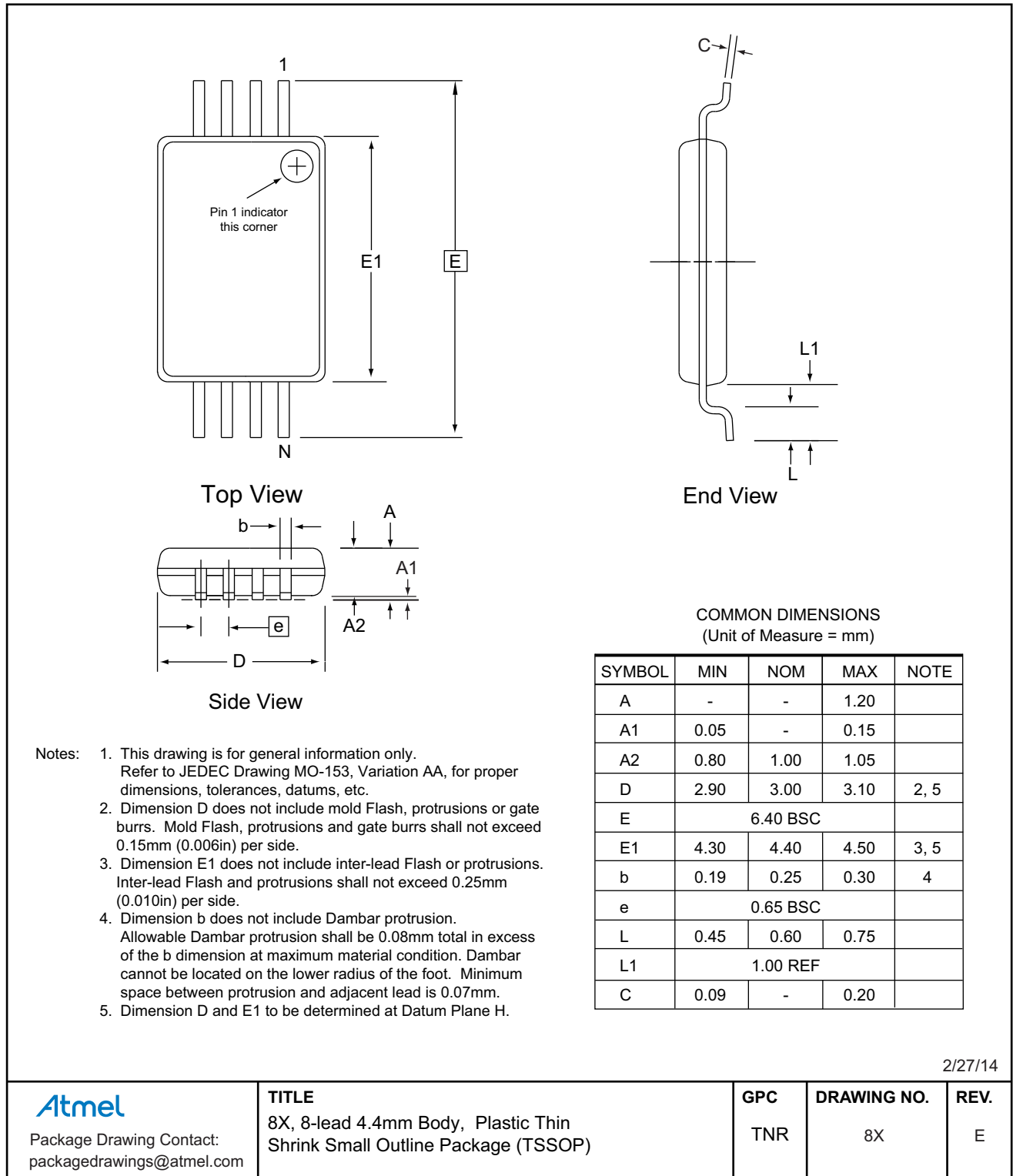
Package Type	
8S1	8-lead, 0.15" wide, Plastic Gull Wing Small Outline (JEDEC SOIC)
8X	8-lead, 4.40mm body, Plastic Thin Shrink Small Outline Package (TSSOP)

11. Packaging Information

11.1 8S1 — 8-lead JEDEC SOIC



11.2 8X — 8-lead TSSOP



12. Revision History

Doc. Rev.	Date	Comments
8674C	10/2014	Update the 8S1 and the 8A2 to 8X packages, template, Atmel logos, and disclaimer page. No change in functional specification.
8674B	10/2009	Updated Lit number and date and removed preliminary status.
8674A	4/2009	Initial document release.



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